

High-Order Dual-Port Quasi-Absorptive Microstrip Coupled-Line Bandpass Filters

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Abstract—In this paper, we present the first demonstration of distributed and symmetrical all-band quasi-absorptive filters that can be designed to arbitrarily high orders. The proposed quasi-absorptive filter consists of a bandpass section (reflective-type coupled-line filter) and absorptive sections (a matched resistor in series with a shorted quarter-wavelength transmission line). Through detailed analysis, we show that the absorptive sections not only eliminate out-of-band reflections but also determine the passband bandwidth. As such, the bandpass section mainly determines the out-of-band roll-off and the order of the filter can be arbitrarily increased without affecting the filter bandwidth by cascading more bandpass sections. A set of 2.45-GHz 1-, 2-, and 3-pole quasi-absorptive microstrip bandpass filters are designed and measured. The filters show simultaneous input and output absorption across both the passband and the stopband. Measurement results agree very well with the simulation and validate the proposed design concept.

Index Terms—Absorptive filter, bandpass filter(BPF), coupled lines, microstrip filter.

I. INTRODUCTION

FILTERS are essential building blocks of nearly every modern RF/microwave system. Conventional microwave filters reject undesired signals in the stopband by presenting a reactive impedance, i.e. the filters are reflective in the stopband. In practice, the reflective nature of these filters may present a system level problem when connected to non-linear circuits such as power amplifiers and mixers. In many cases, the performance of these non-linear circuits are sensitive to out-of-band impedances, particularly those at the harmonics. As such, the use of reflective filters may result in unpredicted system performance degradation such as loss of efficiency, excessive spurious signal levels, and loss of dynamic range [1], [2].

Conventional solutions to this problem involve using attenuators or non-reciprocal components, such as isolators

and circulators, to reduce the reflections of undesired spurious signals, albeit at the obvious cost of significant signal loss, cost, size, and weight of the system. Recently, the concept of “*absorptive*” or “*reflectionless*” filters has been proposed as a viable alternative solution that promises lower overall system performance degradation [3]. In an absorptive filter, the port impedances are well matched both in-band and out-of-band. While the in-band signals pass through the filter with minimal insertion loss, the out-of-band signals are not reflected but attenuated inside the filter.

The idea of absorptive filters was first introduced in [4] as a “non-reflecting branching filter”. The filter consists of two hybrid junctions, two identical reflective-type bandpass filters (BPFs) tuned to the absorption band, and two quarter-wavelength waveguides. Later, traveling-wave directional filters are reported to achieve input-port reflectionless performance [5], [6]. The cascaded microstrip directional filters [7] and miniaturized half-mode substrate integrated waveguide directional filter [8] also achieve one-port quasi-absorptive responses. Here, we use “*quasi-absorptive*” to indicate that the reflection from the filter is not ideally zero but a practically small value. Because the two couplers are arranged in a loop in these filters, the overall circuits are bulky, bandwidth-limited, and only absorptive at their input port, viz., the output port is still fully reflective in the stopband.

Absorptive filters can also be realized by using the complementary-duplexer architecture consisting of a main and an auxiliary channel with opposite filtering transfer functions [9], [10]. Coupling-matrix based analysis reveals that by loading the auxiliary channel with the system impedance and taking the output node of the main channel as the output terminal of the overall circuit, a filtering network of the same type of the main channel can be realized with theoretically perfect input-reflectionless behavior at all frequencies.

Multiple identical single-stage circuits can be cascaded to improve the passband selectivity at the cost of multiplied circuit size and number of components. Duplexer-style one-port absorptive lowpass filters with arbitrary transfer functions are designed using complementary susceptance cancellation in [11]. The same idea is used to develop microstrip one-port absorptive multiband bandpass and bandstop filters [12], filtering power dividers [13], reconfigurable BPFs [14], and multiplexers [15]. To achieve two-port absorptive filtering responses, one more auxiliary channel can be loaded at the output port [16], [17].

Low-Q lossy resonators are also used to achieve either one-port absorption [18]–[20] or symmetrical two-port

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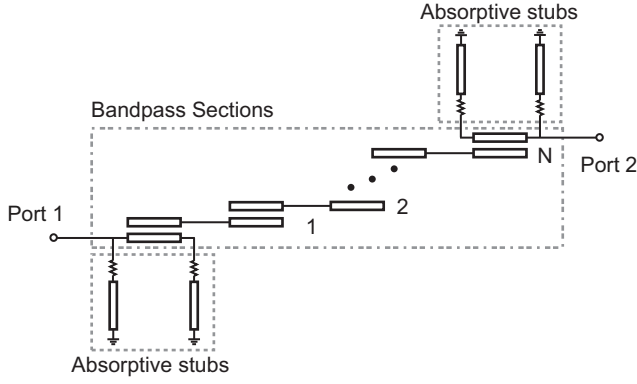


Fig. 1. Conceptual circuit diagram of a N th-order quasi-absorptive BPF using absorptive parallel-coupled feedlines.

absorption [21]–[25] for bandstop filters. Quasi-Gaussian lowpass filter prototypes are reported with both ports reflectionless because of the lossy components in the circuit [26], [27]. A 3.0-GHz distributed quasi-absorptive BPF is presented in [28] by using resistor-loaded lossy resonators as its first resonator to absorb reflection at only one side.

Lumped-element symmetrical two-port absorptive filters are reported in [29]. The design is based on a symmetrical circuit whose even- and odd-mode circuits have equal amplitude reflection coefficients with opposite signs at all frequencies. As a result, the overall circuit is ideally reflectionless for all frequencies. The design results in a large number of circuit elements with tight tolerance requirements. In [30], the concept is extended to support any transfer function by applying proper circuit transformations. In addition, a distributed absorptive BPF is proposed by using Richard's transformations and Kuroda's identity in [31]. However, the distributed absorptive BPF is not reduced to practice due to the extreme transmission-line impedance and coupled lines coupling coefficient [31, Eq. 3].

In [32], symmetric quasi-absorptive microstrip BPFs are implemented based on complementary branch-line bandpass and bandstop filters. A direct in-series cascade of two identical 1-pole stages is proposed to enhance the stopband attenuation with doubled circuit size. Both simulation and measured results show quasi-absorptive behavior in a limited frequency range [32, Fig. 14 and Fig. 16]. Complementary 2-pole bandpass and bandstop structures are also presented, however, the size of the overall circuit is three times the main bandpass section as a result of the two auxiliary bandstop sections.

In this paper, a new quasi-absorptive BPF architecture is proposed and experimentally validated. Fig. 1 shows a conceptual circuit schematic of the proposed filter structure. Bandpass response is realized by parallel coupled lines sections similar to a conventional coupled-line filter. To achieve absorption at all frequencies, absorptive stubs each consisting of a series resistor and a shorted quarter-wavelength stub load the input and output of the coupled-line sections. At the center frequency, these stubs appear as open circuit. Outside of the passband, the stubs appear as matched load

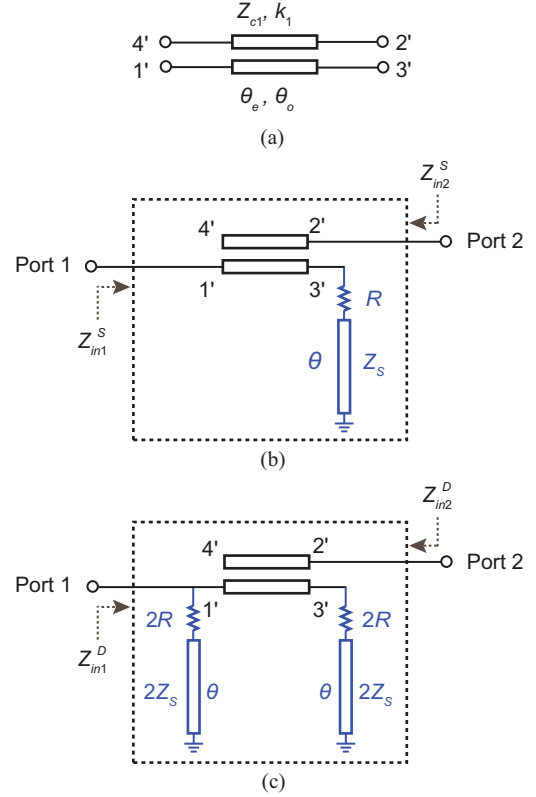


Fig. 2. Evolution of quasi-absorptive coupled-lines. (a) Conventional four-port coupled-lines. (b) One-port quasi-absorptive coupled-line with singly-loaded absorptive stub resistive loading. (c) One-port quasi-absorptive coupled-line with doubly-loaded absorptive stubs.

to the ground and contribute to the absorption of out-of-band signals. Compared with other state-of-the-art absorptive filters, particularly [31] and [32], the proposed architecture is the first that realizes *a distributed and symmetrical all-band absorptive filter that can be extended to arbitrarily high orders*. We validate the proposed concept by demonstrating a set of 2.45-GHz absorptive filters showing 1-, 2-, and 3-pole roll-off characteristics. In all cases, measurement results match very well with the simulation.

II. QUASI-ABSORPTIVE COUPLED LINES

This section introduces the concept and design of quasi-absorptive coupled lines which forms the basis of the proposed quasi-absorptive filters.

Fig. 2(a) shows a section of conventional parallel-coupled lines with the four ports labeled by $1'$, $2'$, $3'$, and $4'$. Z_{c1} and k_1 are the coupled impedance and coupling coefficient, respectively. The coupled lines have an even-mode impedance $Z_{e1} = Z_{c1}k_1$ and an odd-mode impedance $Z_{o1} = Z_{c1}/k_1$. θ_e and θ_o are the even- and odd-mode electrical length, respectively [33]. To simplify the model and the analysis, $\theta_e = \theta_o = 90^\circ$ at the center frequency. For simplicity, Normalized frequency f/f_0 is used in the circuit analysis, where f_0 is the filter passband center frequency.

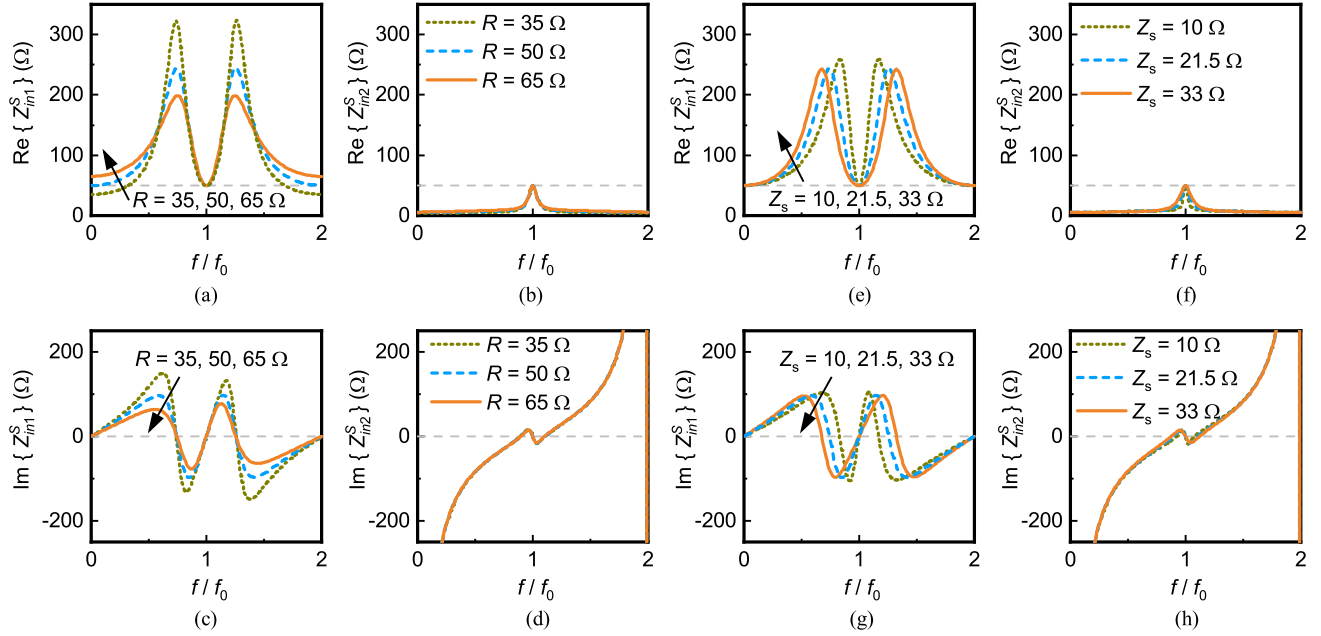


Fig. 3. Input impedance analysis of singly-loaded coupled line with respect to R and Z_s ($Z_{c1} = 98 \Omega$, $k_1 = 1.63$, and $Z_{o1} = Z_{o2} = 50 \Omega$). (a)–(d) shows the calculated frequency dependence of $\text{Re}\{Z_{in1}^S\}$, $\text{Im}\{Z_{in1}^S\}$, $\text{Re}\{Z_{in2}^S\}$, and $\text{Im}\{Z_{in2}^S\}$, respectively, for various R values ($Z_s = 21.5 \Omega$). (e)–(h) shows the calculated frequency dependence of $\text{Re}\{Z_{in1}^S\}$, $\text{Im}\{Z_{in1}^S\}$, $\text{Re}\{Z_{in2}^S\}$, and $\text{Im}\{Z_{in2}^S\}$, respectively, for various Z_s values ($R = 50 \Omega$).

The impedance matrix of the conventional four-port parallel-coupled line structure can be expressed as in [34]

$$\begin{bmatrix} V_{1'} \\ V_{2'} \\ V_{3'} \\ V_{4'} \end{bmatrix} = \begin{bmatrix} Z_{1'1'} & Z_{1'2'} & Z_{1'3'} & Z_{1'4'} \\ Z_{2'1'} & Z_{2'2'} & Z_{2'3'} & Z_{2'4'} \\ Z_{3'1'} & Z_{3'2'} & Z_{3'3'} & Z_{3'4'} \\ Z_{4'1'} & Z_{4'2'} & Z_{4'3'} & Z_{4'4'} \end{bmatrix} \begin{bmatrix} I_{1'} \\ I_{2'} \\ I_{3'} \\ I_{4'} \end{bmatrix}, \quad (1)$$

where

$$Z_{1'1'} = Z_{2'2'} = Z_{3'3'} = Z_{4'4'} = -j \frac{Z_{c1}}{2} \left(k_1 + \frac{1}{k_1} \right) \cot \theta, \quad (2a)$$

$$Z_{1'2'} = Z_{2'1'} = Z_{3'4'} = Z_{4'3'} = -j \frac{Z_{c1}}{2} \left(k_1 - \frac{1}{k_1} \right) \csc \theta, \quad (2b)$$

$$Z_{1'3'} = Z_{3'1'} = Z_{2'4'} = Z_{4'2'} = -j \frac{Z_{c1}}{2} \left(k_1 + \frac{1}{k_1} \right) \csc \theta, \quad (2c)$$

$$Z_{1'4'} = Z_{4'1'} = Z_{2'3'} = Z_{3'2'} = -j \frac{Z_{c1}}{2} \left(k_1 - \frac{1}{k_1} \right) \cot \theta. \quad (2d)$$

Coupled-line sections with one or two ports terminated in open circuit, short circuit, or matched load are widely used as building blocks for reflective filters [35]. In such filters, signals in the stopband sees a reactive impedance and is fully reflected.

In this work, we propose quasi-absorptive coupled lines as building blocks for quasi-absorptive BPFs. Shown in Fig. 2 (b) and Fig. 2 (c), the coupled-line section is loaded with one or two resonant absorptive stubs.

In Fig. 2 (b), the absorptive stub consists of a resistor R and a shorted stub with a characteristic impedance of Z_s

and an electrical length of θ . In Fig. 2 (c), the absorptive stub in Fig. 2 (b) is split into two identical absorptive stubs that load both ends of one of the coupled-lines. The following sub-sections analyze the characteristics of these two circuits.

A. Quasi-Absorptive Coupled Lines with a Single Absorptive Stub

In Fig. 2 (b), Port 1' and Port 2' act as the input and output ports of the circuit. Port 4' is open-ended and Port 3' is loaded by an absorptive branch. Z_{in1} and Z_{in2} are defined as the input impedance at Port 1 and Port 2, respectively.

Applying the boundary conditions $I_{4'} = 0$ and $V_{3'} = -Z_{stub}^S I_{3'}$ to (1), we have

$$\begin{bmatrix} I_{3'} \\ I_{4'} \end{bmatrix} = \begin{bmatrix} -\frac{Z_{1'3'}}{Z_{1'1'} + Z_{stub}^S} & -\frac{Z_{1'4'}}{Z_{1'1'} + Z_{stub}^S} \\ 0 & 0 \end{bmatrix} \begin{bmatrix} I_{1'} \\ I_{2'} \end{bmatrix}, \quad (3)$$

where $Z_{stub}^S = R + jZ_s \tan \theta$. Substituting (3) into (1) yields the two-port impedance matrix \mathbf{Z}^b whose element values are

$$Z_{11}^S = Z_{1'1'} - \frac{Z_{1'3'}^2}{Z_{1'1'} + Z_{stub}^S}, \quad (4a)$$

$$Z_{12}^S = Z_{21}^S = Z_{1'2'} - \frac{Z_{1'4'} Z_{1'3'}}{Z_{1'1'} + Z_{stub}^S}, \quad (4b)$$

$$Z_{22}^S = Z_{2'2'} - \frac{Z_{1'4'}^2}{Z_{1'1'} + Z_{stub}^S}. \quad (4c)$$

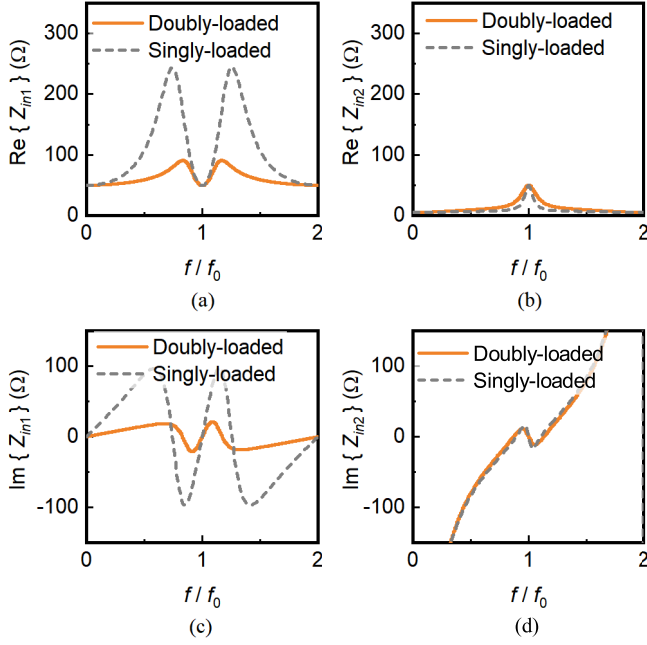


Fig. 4. Comparison between the calculated input impedance profiles of the singly-loaded [Fig. 2 (b)] and the doubly-loaded [Fig. 2 (c)] quasi-absorptive coupled lines ($Z_{c1} = 98 \Omega$, $Z_s = 21.5 \Omega$, $k_1 = 1.63$, $R = 50 \Omega$, $Z_0 = 50 \Omega$). (a) $\text{Re}\{Z_{in1}\}$. (b) $\text{Re}\{Z_{in2}\}$. (c) $\text{Im}\{Z_{in1}\}$. (d) $\text{Im}\{Z_{in2}\}$.

The input impedance of a general two port network can be extracted from its Z -parameters as

$$Z_{in1} = Z_{11} - \frac{Z_{12}Z_{21}}{Z_{22} + Z_0}, \quad (5a)$$

$$Z_{in2} = Z_{22} - \frac{Z_{12}Z_{21}}{Z_{11} + Z_0}, \quad (5b)$$

where Z_0 is the port impedance and is set to 50Ω in this paper.

Taking (2) and (4) into (5) gives us the synthesized port impedance Z_{in1}^S and Z_{in2}^S for the single-absorptive-stub loaded coupled-line. It is obvious that both Z_{in1}^S and Z_{in2}^S are frequency-dependent functions of the four design parameters Z_{c1} , k_1 , Z_s , and R . Explicit expressions of Z_{in1}^S and Z_{in2}^S in terms of the above parameters may be derived but are too complicated to give design insights, except at a few specific frequencies. For example, by setting $\theta = \pi/2$ for the center frequency f_0 in (2), (4), and (5), we have

$$Z_{in1}^S|_{f_0} = Z_{in2}^S|_{f_0} = \frac{Z_{c1}^2(k_1 - 1/k_1)^2}{4Z_0}, \quad (6)$$

which is the same as the conventional coupled-line circuit [33]. At the same time, $\theta = n\pi$ for the even harmonics $2nf_0$, ($n = 0, 1, 2, \dots$), we have

$$Z_{in1}^S|_{2nf_0} = R, \quad (7a)$$

$$Z_{in2}^S|_{2nf_0} = -j\infty. \quad (7b)$$

To better understand the characteristics of the absorptive coupled lines, we present in Fig. 3 a numerical study of the port input impedances in terms of the design parameters. Several observations can be made.

- 1) Unlike conventional coupled lines, Port 1 of the quasi-absorptive coupled lines can be impedance matched not only at f_0 but also at dc and the even harmonics. From (6) and (7), we can see that a perfect match can be achieved at any multiples of f_0 by the proper choice of Z_{c1} , k_1 , and R [Fig. 3 (a) and Fig. 3 (c)]. On the other hand, Port 2 of the quasi-absorptive coupled lines is matched only at the odd multiples of f_0 .
- 2) The maximum mismatch of Port 1 is highly dependent on R [Fig. 3 (a) and Fig. 3 (c)] and relatively independent of Z_s [Fig. 3 (e) and Fig. 3 (g)]. A larger R leads to a lower maximum mismatch at the penalty of a higher mismatch at the even harmonics. The choice of R is dependent on the application. In some applications, e.g., after a strong nonlinear amplifier, it may be desirable to have high absorptive performance at the even harmonics, therefore mandating $R = Z_0$. Z_{in2}^S is almost entirely determined by the coupled lines and independent of the absorptive stub (R and Z_s). We note that the absolute maximum mismatch for the singly-loaded quasi-absorptive coupled lines is still quite high, a problem that we seek to solve in the next sub-section.
- 3) The matching bandwidth of Port 1 around f_0 is almost independent of R but is a strong function of Z_s . Shown in Fig. 3 (e) and Fig. 3 (g), Z_s affects the rate of change of both the real and imaginary parts of Z_{in1}^S at f_0 . As will be shown in Section III, this property is used to control the passband bandwidth of the absorptive filters presented in this work.
- 4) Intuitively, the different matching characteristics of Port 1 and Port 2 may be understood by observing that the absorptive stub is connected with Port 1 through a quarter-wavelength transmission line, such that the input resistance and reactance at Port 1 vary in a relative smaller range when compared with these at Port 2.

B. Quasi-Absorptive Coupled Lines With Two Absorptive Stubs

To improve the absorption performance across all bandwidth, the single absorptive stub can be split into two identical stubs that load both ends of the coupled lines, as shown in Fig. 2 (c).

Following the same procedures in Section II-A, the impedance matrix \mathbf{Z}^D for doubly-loaded quasi-absorptive coupled lines can be derived

$$Z_{11}^D = \frac{Z_{stub}^D M}{M + Z_{stub}^D}, \quad (8a)$$

$$Z_{12}^D = Z_{21}^D = \frac{Z_{stub}^D N}{M + Z_{stub}^D}, \quad (8b)$$

$$Z_{22}^D = P - \frac{N^2}{M + Z_{stub}^D}, \quad (8c)$$

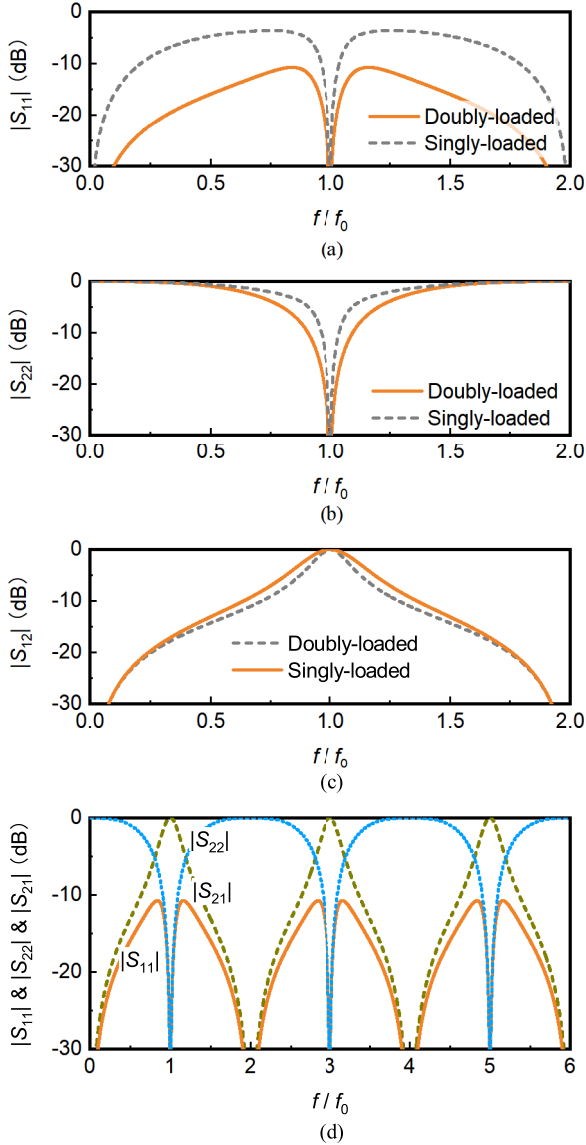


Fig. 5. Comparisons of the singly-loaded [Fig. 2(b)] and the doubly-loaded [Fig. 2(c)] quasi-absorptive coupled lines in terms of calculated S -parameters ($Z_{c1} = 98 \Omega$, $Z_s = 21.5 \Omega$, $k_1 = 1.63$, $R = 50 \Omega$, $Z_0 = 50 \Omega$): (a) $|S_{11}|$, (b) $|S_{22}|$, and (c) $|S_{12}|$. (d) Wideband S -parameters of the doubly-loaded quasi-absorptive coupled lines.

where

$$Z_{stub}^D = 2(R + jZ_s \tan\theta), \quad (9a)$$

$$M = Z_{1'1'} - \frac{Z_{1'3'}^2}{Z_{1'1'} + Z_{stub}^D}, \quad (9b)$$

$$N = Z_{1'2'} - \frac{Z_{1'4'}Z_{1'3'}}{Z_{1'1'} + Z_{stub}^D}, \quad (9c)$$

$$P = Z_{2'2'} - \frac{Z_{1'4'}^2}{Z_{1'1'} + Z_{stub}^D}. \quad (9d)$$

The port input impedances Z_{in1}^D and Z_{in2}^D can be obtained by taking (2), (8), and (9) into (5). The input impedances of doubly-loaded quasi-absorptive coupled lines are found to be exactly the same with those of the singly-loaded circuit at any

multiples of f_0 , as given in (6) and (7). In other words, both can be fully matched not only at f_0 but also at any harmonic frequencies.

Fig. 4 shows a comparative study of the impedance profiles of the singly- and doubly-loaded quasi-absorptive coupled lines while Fig. 5 compares their S -parameters. Some observations can be made.

- 1) It can be seen from Fig. 4(a) that Port 1 of the doubly-loaded circuit has a much smaller impedance variation (real part of 50Ω to 89Ω and imaginary part of -21Ω to 21Ω) than that of the singly-load circuit (real part of 50Ω to 245Ω and imaginary part of -100Ω to $+100 \Omega$). This leads to a much reduced reflection, i.e., improved absorption, at Port 1 for all frequencies, as shown in Fig. 5 (a),
- 2) Similar to the singly-loaded quasi-absorptive coupled lines, Port 2 of the doubly-loaded circuit resembles the reflective characteristics of conventional coupled lines. Fig. 4(b) shows that the $\text{Re}\{Z_{in2}\}$ of doubly-loaded quasi-absorptive coupled lines has a slightly less rate of change than that of the singly-loaded quasi-absorptive coupled lines, contributing to a wider matching and transmission bandwidth around f_0 as shown in Fig. 5 (b) and Fig. 5 (c), respectively.
- 3) Unlike the distributed branch-line filters in [9] and [32], which are quasi-absorptive in a limited frequency range, the proposed quasi-absorptive coupled lines consist of quarter-wavelength transmission lines and have periodic frequency responses [33]. Fig. 5 (d) shows that all-band quasi-absorptive can be obtained at Port 1 with spectral period of $[0, 2f_0)$. The spurious passband occurs at the odd harmonic frequencies and the stopband at the even harmonic frequencies are all suppressed by the periodic transmission zeros of the coupled lines [35]. This unique all-band quasi-absorptive property of the doubly-loaded coupled-lines will be used in the design of distributed all-band quasi-absorptive BPFs in Section III.
- 4) Another benefit of splitting the absorptive stub that may not be immediately obvious is that it allows easier microstrip implementation. As will be detailed in Section III-A, the optimized value of Z_s ($Z_s = 21.5 \Omega$) is too low for microstrip implementation. By splitting the absorptive stub into two identical sections, both R and Z_s double in value. A characteristic impedance of 43Ω is much easier to realize.

III. QUASI-ABSORPTIVE FILTERS

The proposed quasi-absorptive parallel-coupled lines will be applied to design quasi-absorptive BPFs in this section. First, basic 1-pole quasi-absorptive BPF is explored and detailed parametric studies are carried out to illustrate its unique performance and the optimization method. Subsequently, higher-order (e.g., 2-pole and 3-pole) topologies through the basic 1-pole quasi-absorptive BPF are presented and studied. Detailed design and optimization procedures are accordingly provided. Finally, a comparison between the reported distributed quasi-absorptive BPFs and this work is

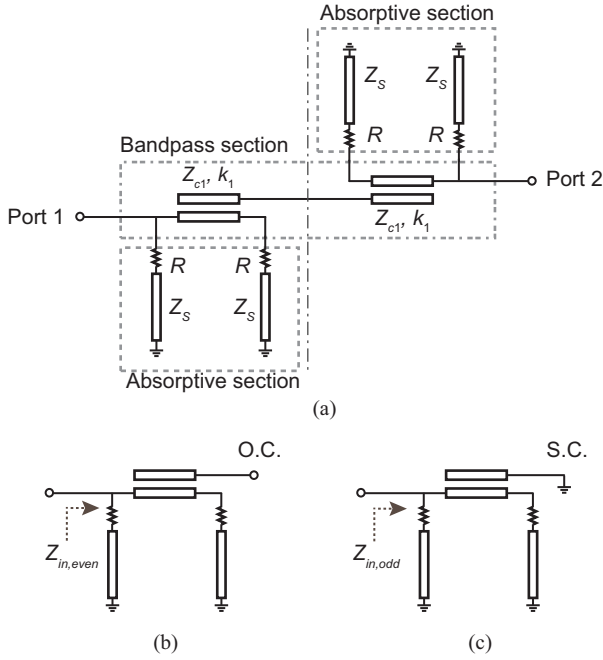


Fig. 6. (a) Transmission line circuit model of the 1-pole quasi-absorptive BPF. (b) Equivalent even-mode circuit with open-circuit (O.C.) termination. (c) Equivalent odd-mode circuit with short-circuit (S.C.) termination.

given to illustrate the advantages and disadvantages of the presented work.

A. 1-Pole Quasi-Absorptive BPFs

The doubly-loaded quasi-absorptive coupled lines presented in Section II-B are quasi-absorptive in only one of their two ports. By connecting two doubly-loaded quasi-absorptive coupled lines back-to-back, a symmetrical quasi-absorptive network can be created as shown in Fig. 6. Apparently, this circuit resembles a half-wavelength resonator coupled through quarter-wavelength coupled lines [labeled as “bandpass section” in Fig. 6(a)]. The difference is the four absorptive stubs added to the input and output feedlines [labeled as “absorptive section” in Fig. 6(b)].

We will analyze this 1-pole filter (coupled resonator) circuit to understand its characteristics and design trade-offs. Because the circuit is symmetric, it can be analyzed using the even-odd mode analysis. Fig. 6(b) and Fig. 6(c) show the even- and odd-mode circuit, respectively. The even- and odd-mode input impedance can be derived from two port impedance matrix as

$$Z_e = Z_{11}, \quad (10a)$$

$$Z_o = Z_{11} - \frac{Z_{12}Z_{21}}{Z_{22}}, \quad (10b)$$

where Z_{ij} are the Z-parameters of the doubly-loaded quasi-absorptive coupled lines given in (8). From (10), the S-parameters of the 1-pole quasi-absorptive BPF can be readily derived.

For illustration purposes, S-parameters of an example 1-pole quasi-absorptive BPF are shown in Fig. 7. As a comparison, the S-parameters of the same circuit but without the absorptive

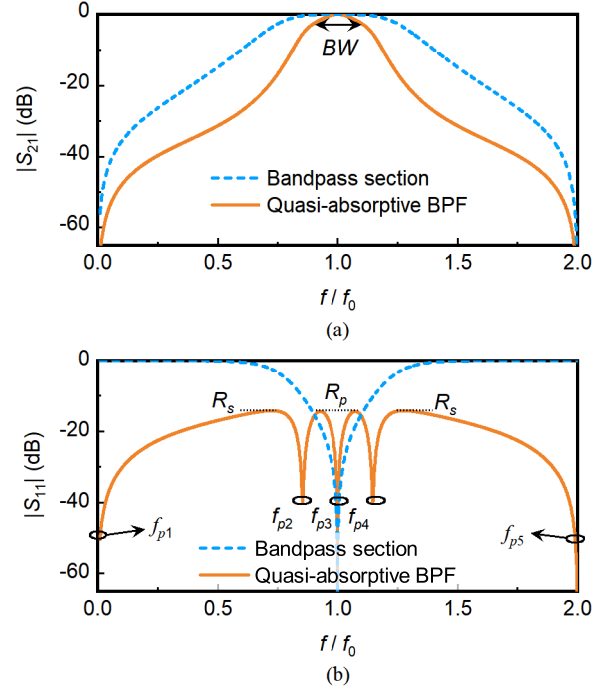


Fig. 7. (a) Simulated $|S_{21}|$ of the 1-pole quasi-absorptive BPF and its bandpass section. (b) Simulated $|S_{11}|$ of the 1-pole quasi-absorptive BPF and its bandpass section.

stubs are also shown in Fig. 7. The 1-pole quasi-absorptive BPF shows quasi-absorptive responses with return loss better than 13 dB at all frequencies. Due to the presence of the absorptive stubs, the in-band transmission flatness is degraded. The absorptive stubs also lead to a much narrower passband in the 1-pole quasi-absorptive BPF when compared with its “bandpass section” only. This is generally true for other reported absorptive/reflectionless BPFs [9], [31], [32].

A few variables are labeled in Fig. 7 to facilitate a more detailed analysis later on. BW , R_s , and R_p are the 3-dB bandwidth of the passband, maximum stopband reflection, and maximum passband reflection, respectively. FBW is defined as the fractional 3-dB bandwidth, viz., $FBW = BW/f_0$. Five reflection zeros can be observed in the range of dc–2.0 GHz. Three of them, f_{p1} , f_{p3} , and f_{p5} , are located at dc, f_0 , and $2f_0$, respectively. Another two reflection zeros (f_{p2} and f_{p4}) are symmetrically located around f_0 .

Although theoretical expressions for the transmission and reflection characteristics of the 1-pole quasi-absorptive BPF can be derived, they are too complicated to give design insights. Therefore, Fig. 8 presents parametric studies of the characteristics of the 1-pole quasi-absorptive BPF. Fig. 8(a), Fig. 8(b), and Fig. 8(c) show the locations of the reflection zeros with respect to Z_s , k_1 , Z_{c1} , respectively. Fig. 8(d)–(f) and Fig. 8(g)–(i) show the corresponding change in the reflection level and 3-dB bandwidth, respectively. In these figures, f_{p1} and f_{p5} are not shown because they are fixed at dc and $2f_0$.

When the transmission-line-stub impedance Z_s increases from 12.5Ω to 32.5Ω , a large increase of FBW can be

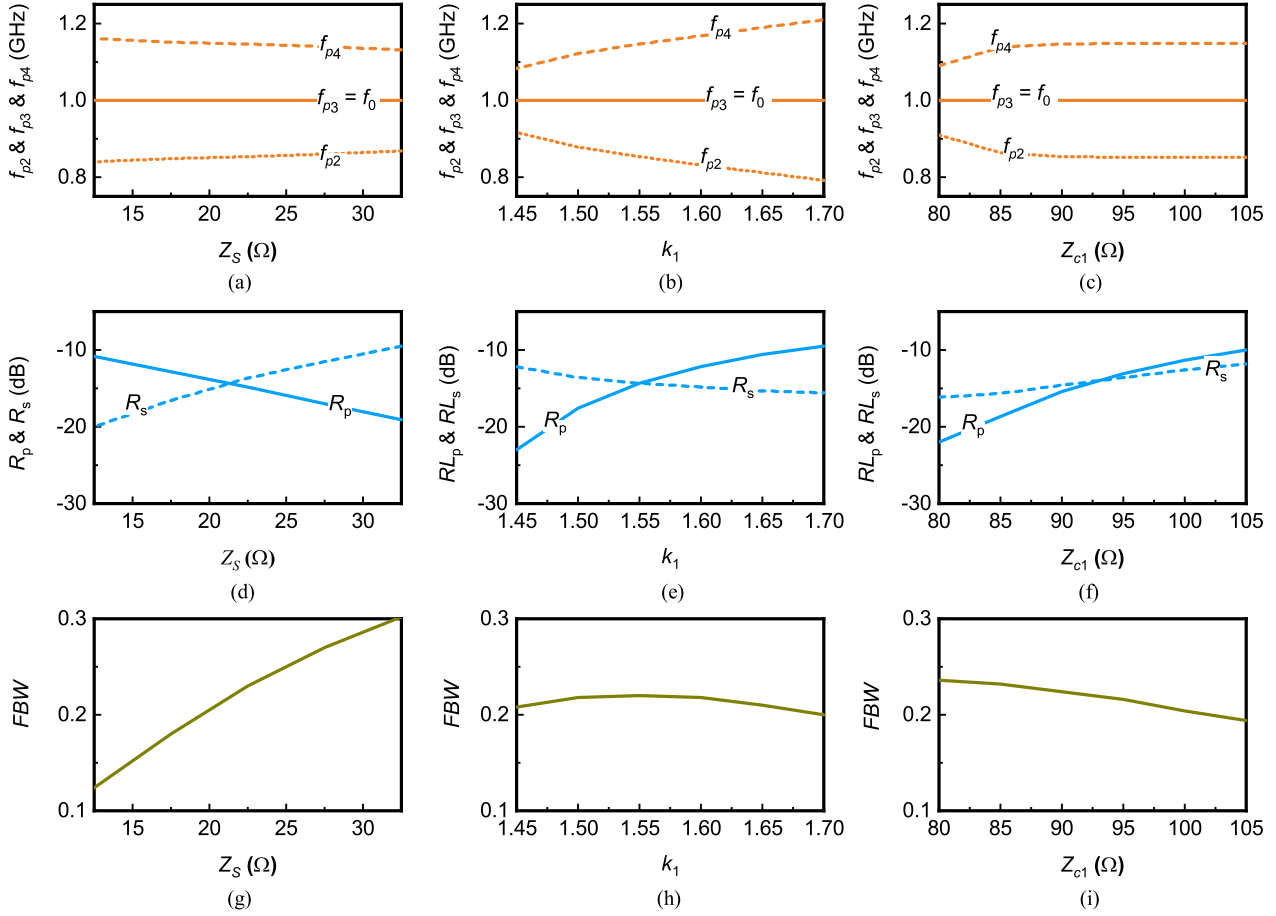


Fig. 8. Parametric studies of the 1-pole quasi-absorptive BPF. (a) Reflection poles versus Z_s ($k_1 = 1.55$, $Z_{c1} = 92 \Omega$, $R = 50 \Omega$). (b) Reflection poles versus coupling coefficient k_1 ($Z_s = 21.5 \Omega$, $Z_{c1} = 92 \Omega$, $R = 100 \Omega$). (c) Reflection poles versus coupling impedance Z_{c1} ($Z_s = 21.5 \Omega$, $k_1 = 1.55$, $R = 50 \Omega$). (d) In-band reflection R_p and out-of-band reflection R_s versus stub impedance Z_s ($k_1 = 1.55$, $Z_{c1} = 92 \Omega$, $R = 50 \Omega$). (e) In-band reflection R_p and out-of-band reflection R_s versus coupling coefficient k_1 ($Z_s = 21.5 \Omega$, $Z_{c1} = 92 \Omega$, $R = 50 \Omega$). (f) In-band reflection R_p and out-of-band reflection R_s versus coupling impedance Z_{c1} ($Z_s = 21.5 \Omega$, $k_1 = 1.55$, $R = 50 \Omega$). (g) FBW versus stub impedance Z_s ($k_1 = 1.55$, $Z_{c1} = 92 \Omega$, $R = 50 \Omega$). (h) FBW versus coupling coefficient k_1 ($Z_s = 21.5 \Omega$, $Z_{c1} = 92 \Omega$, $R = 50 \Omega$). (i) FBW versus coupling impedance Z_{c1} ($Z_s = 21.5 \Omega$, $k_1 = 1.55$, $R = 50 \Omega$).

observed from 12% to 30% with deteriorated R_s . The two reflection zeros f_{p2} and f_{p4} move slightly closer to f_{p3} , resulting in an improved R_p .

As the coupling coefficient k_1 increases from 1.45 to 1.70, f_{p2} and f_{p4} move away from f_0 , leading to an increased R_p and decreased R_s . Interestingly, the bandwidth of the 1-pole quasi-absorptive BPF is almost independent of k_1 , where as it is well known that the coupling coefficient k in the conventional coupled-line BPFs can be effectively used to control the filter bandwidth [35]. This is because the bandwidth of the 1-pole quasi-absorptive BPF is primarily determined by the absorptive stubs. In fact, this can be seen in Fig. 7 (a). For the corresponding k_1 values, the bandwidth of the bandpass section [Fig. 6 (a)] is much wider than that of the 1-pole quasi-absorptive BPF itself.

FBW increases from 19% to 23% as Z_{c1} decreases from 105 Ω to 80 Ω with a corresponding improvement of both R_s and R_p . f_{p2} , f_{p3} , and f_{p4} remain relatively unchanged for Z_{c1} above 85 Ω . When Z_{c1} falls below approximately 80 Ω ,

f_{p2} and f_{p4} become complex, as will be shown in Fig. 10.

For all the variable ranges studied, there is always a combination that results in $R_s = R_p$ [Fig. 8 (d)–(f)], viz., equal in-band and out-of-band reflection ripple. Since Z_s primarily determines the bandwidth, an equi-ripple-reflection design can be achieved by adjusting k_1 and Z_{c1} . To demonstrate this, Table I and Fig. 9 respectively show the design parameters and S-parameters of three equal-ripple-reflection 1-pole quasi-absorptive BPF designs with different FBW . The 1-pole quasi-absorptive BPF with equal-ripple reflection will be used as the starting point for the extension to higher-order quasi-absorptive BPF designs (Section III-B).

If desired, slightly decreasing Z_{c1} can further reduce the in-band reflection level while maintaining nearly the same passband bandwidth. To see this, Table II and Fig. 10 respectively show the design parameters and S-parameters of three slightly modified designs with improved in-band matching but nearly the same bandwidth as those in Table I and Fig. 9.

TABLE I
INITIAL DESIGNS FOR 1-POLE
QUASI-ABSORPTIVE BPF

Design	FBW	R_p dB	R_s dB	Z_{c1} (Ω)	k_1	Z_s (Ω)
1	27%	-13.0	-13.0	92	1.62	26.5
2	22%	-14.3	-14.3	92	1.55	21.5
3	17%	-15.8	-15.8	92	1.48	16.5

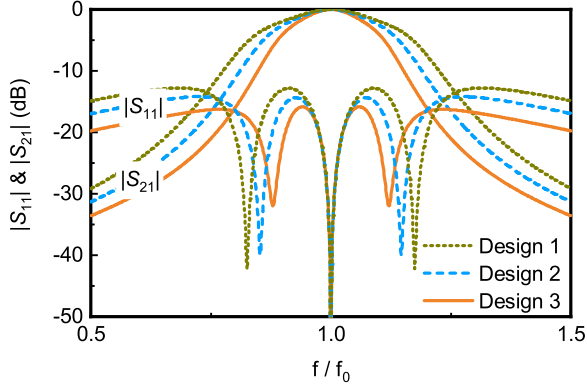


Fig. 9. Simulated S-parameters of the 1-pole quasi-absorptive BPF with different FBW and equal reflection ripple $R_s = R_p$.

TABLE II
DESIGNS FOR 1-POLE QUASI-ABSORPTIVE BPF
WITH IMPROVED MATCHING

Design	FBW	R_p dB	R_s dB	Z_{c1} (Ω)	k_1	Z_s (Ω)
1'	28%	-15.6	-14.6	82	1.62	26.5
2'	23%	-19.5	-15.9	84	1.55	21.5
3'	18%	-20.0	-17.9	86	1.48	16.5

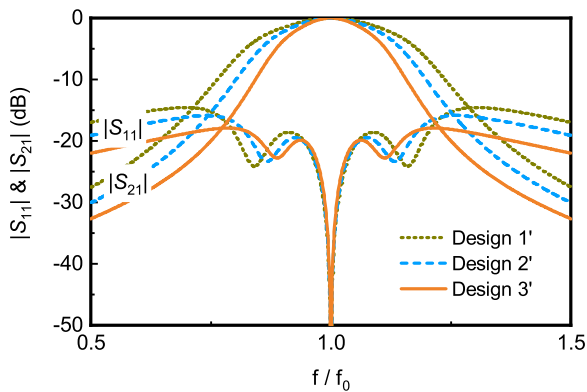


Fig. 10. Improved matching from Fig. 9 by tuning the impedance Z_{c1} .

B. Extension to Higher-Order Quasi-Absorptive BPFs

In conventional reflective-type filters, increasing the filter order is realized by coupling more resonators in the main signal path [35]. Similarly, the proposed quasi-absorptive BPFs architecture can be extended to higher order by increasing

the order of the bandpass section. Fig. 11 (a) and Fig. 11 (f) show examples of a 2-pole and a 3-pole equal-ripple-reflection quasi-absorptive BPFs. Z_{e2} and Z_{o2} are the respective coupled even- and odd-mode impedance of the coupled-line section for higher-order implementation. All the other circuit parameters are the same as Design 2 of Table I, viz., $Z_{c1} = 92 \Omega$, $Z_s = 21.5 \Omega$, $Z_0 = 50 \Omega$, $R = 50 \Omega$, and $k_1 = 1.55$.

Similar to the 1-pole case, the bandwidth of the higher-order quasi-absorptive filters are primarily determined by Z_s of the absorptive stubs. The coupled lines in the bandpass section are essentially independent from the quasi-absorptive coupled lines at the input and output of filter. In other words, the bandwidth of the filter is mainly set by the quasi-absorptive coupled lines, while the filter roll-off is mainly set by the bandpass coupled lines. As such, one can simply increase the filter order by cascading more coupled lines sections without affecting the bandwidth of the filter.

Fig. 11 (b)–(c) and Fig. 11 (g)–(h) show the 2-pole and 3-pole filter responses with varied coupled impedance Z_{c2} and coupling coefficient k_2 . -13 dB equal-ripple reflection level can be attained for both 2-pole and 3-pole quasi-absorptive BPFs by using the same coupled-line parameters Z_{c2} and k_2 . Similar to the 1-pole quasi-absorptive BPF case, the in-band reflection can be improved by adjusting Z_{c1} without changing the passband FBW, as shown in Fig. 11 (d)–(e) and Fig. 11 (i)–(j).

Frequency responses of the 1-, 2-, and 3-pole quasi-absorptive filters are given in Fig. 12 for comparison. The circuit values for 1-pole filter are the same as Design 2 of Table I. The coupled-line parameters for higher-order extensions are identical and set to $Z_{c2} = 100 \Omega$ and $k_2 = 1.32$. With the same circuit parameters, different-order quasi-absorptive filters have the same FBW and maintain equal-ripple-reflection responses. However, both the stopband attenuation and passband roll-off are accordingly improved as the order increases. Besides, all-band quasi-reflectionless at both input and output ports can be attained, however, at the cost of deteriorated in-band transmission flatness. The deterioration is due to the fact that the loaded absorption resistors are resonance-dependent and only equivalently opened at the center frequency f_0 . Future work can be focused on symmetrical quasi-absorptive BPFs with improved passband transmission flatness by using quasi-absorptive circuits that can be equivalently opened in a wide frequency range.

Based on these observations, a step-by-step design guideline can be developed and is illustrated in Fig. 13.

- 1) The process starts with a set of initial values for θ , R , and Z_0 . For simplicity, one can set $\theta = 90^\circ$, $Z_0 = 50 \Omega$, and $R = Z_0 = 50 \Omega$.
- 2) Because the absorptive sections remain constant in filters with any order, the optimal values of Z_s , k_1 , and Z_{c1} can be determined using a 1-pole quasi-absorptive BPF with the same bandwidth requirement as the higher-order filter.
 - a) Based on the bandwidth requirement, an initial value of Z_s is determined by parametric analysis of a 1-pole

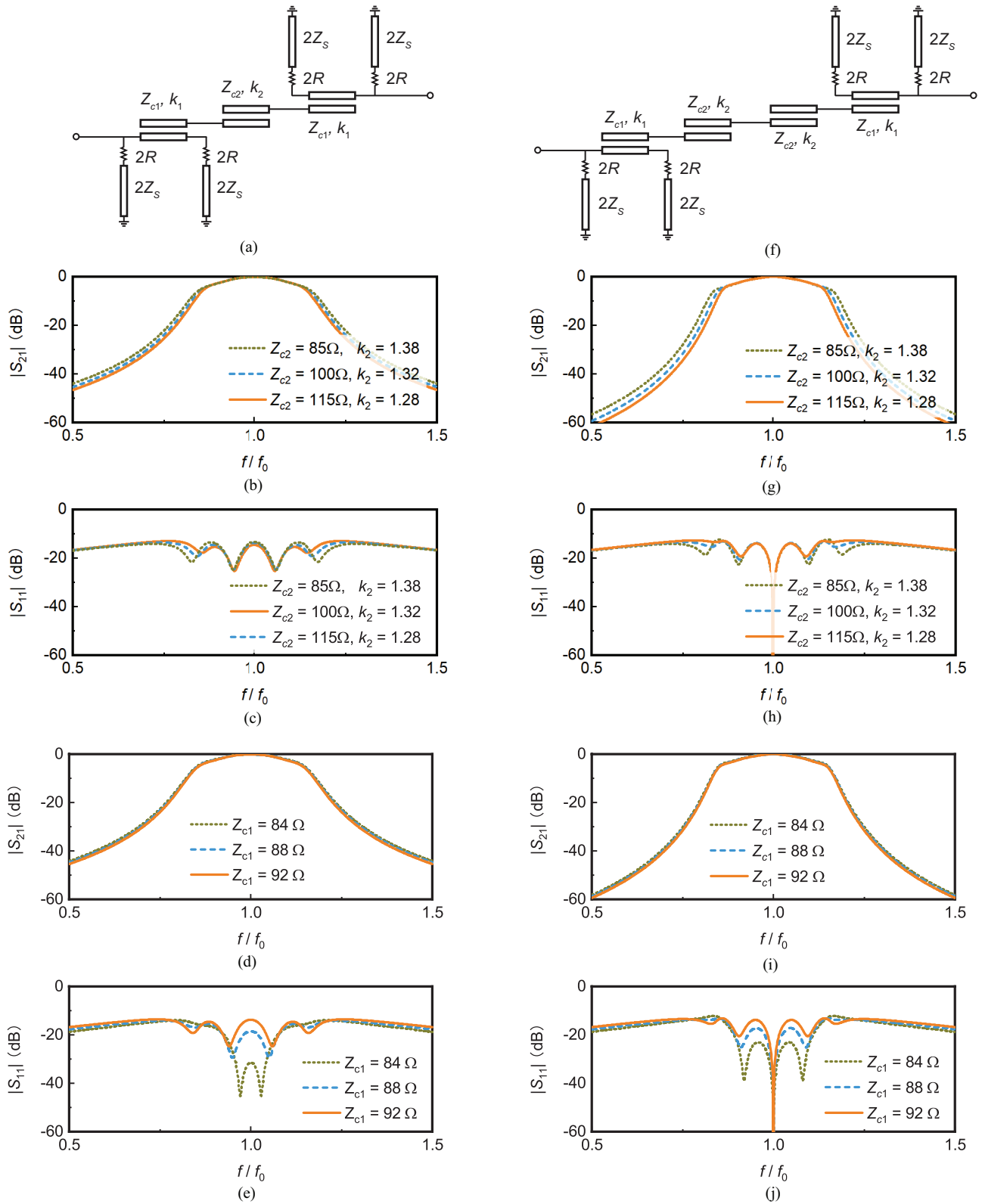


Fig. 11. 2-pole and 3-pole quasi-absorptive filters. (a) Transmission-line circuit model of the 2-pole quasi-absorptive BPF. (b) Simulated $|S_{21}|$ of the 2-pole quasi-absorptive BPF for various Z_{c2} and k_2 . (c) Simulated $|S_{11}|$ of the 2-pole quasi-absorptive BPF for various Z_{c2} and k_2 . (d) Simulated $|S_{21}|$ of the 2-pole quasi-absorptive BPF for various Z_{c1} ($Z_{c2} = 100\Omega$ and $k_2 = 1.32$). (e) Simulated $|S_{11}|$ of the 2-pole quasi-absorptive BPF for various Z_{c1} ($Z_{c2} = 100\Omega$ and $k_2 = 1.32$). (f) Transmission-line circuit model of the 3-pole quasi-absorptive BPF. (g) Simulated $|S_{21}|$ of the 3-pole quasi-absorptive BPF for various Z_{c2} and k_2 . (h) Simulated $|S_{11}|$ of the 3-pole quasi-absorptive BPF for various Z_{c2} and k_2 . (i) Simulated $|S_{21}|$ of the 3-pole quasi-absorptive BPF for various Z_{c1} ($Z_{c2} = 100\Omega$ and $k_2 = 1.32$). (j) Simulated $|S_{11}|$ of the 3-pole quasi-absorptive BPF for various Z_{c1} ($Z_{c2} = 100\Omega$ and $k_2 = 1.32$).

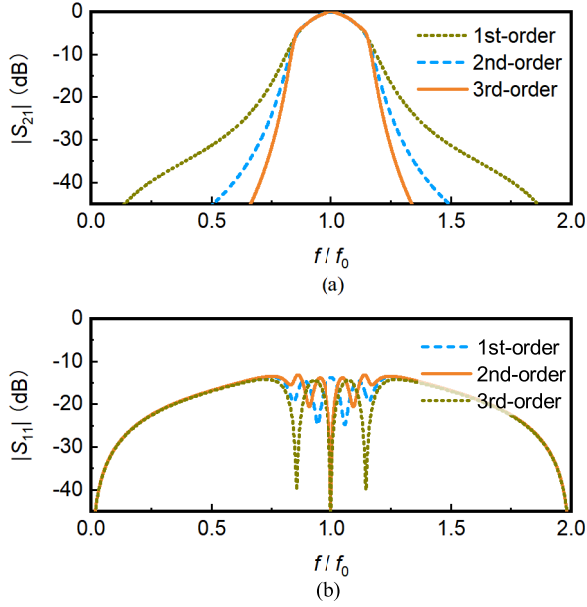


Fig. 12. Simulated frequency responses of the 1-, 2-, and 3-pole quasi-absorptive filters using the same circuit parameters as in Fig. 11. (a) $|S_{21}|$. (b) $|S_{11}|$.

quasi-absorptive BPF, similar to Fig. 8 (g).

- b) Determine Z_{c1} and k_1 to realize an equi-ripple reflection response in a similar fashion as Fig. 8 (b)–(i). Note that Z_{c1} needs to be sufficiently large to ensure that f_{p2} and f_{p4} are real valued.
 - c) Depending on the resulting filter performance from Step b), Z_{c1} , k_1 , and Z_s may need to be slightly adjusted/optimized for an optimal trade-off between bandwidth and reflection level.
- 3) Once the design of the 1-pole quasi-absorptive BPF is finalized, the required filter order $2N$ can be determined from Fig. 12(a) using the 1-pole response as a reference.
 - 4) N coupled lines sections are inserted in the bandpass section to create the N -pole filter. The coupled lines parameters Z_{c2} and k_2 need to be optimized for equal-ripple reflection. If desired, the passband reflection can be improved by slightly reducing Z_{c1} .

C. Comparison With the State-of-the-Art

At the time of writing, only two distributed symmetrical absorptive BPFs have been presented in the literature, the quasi-absorptive BPFs using complementary bandstop-bandpass structures in [32] and the fully-absorptive BPF based on the theory of duality in [31]. Representative circuit diagrams of these two circuits are shown in Fig. 14 (a) and Fig. 14 (b). Note that [32] presents a technology-independent coupling matrix formalism to have symmetrical quasi-reflectionless performances. To make a fair comparison, its proof-of-concept microstrip implementation is compared with the proposed distributed quasi-absorptive filters. We also note that in all three filter structures, a bandpass section and a bandstop section can

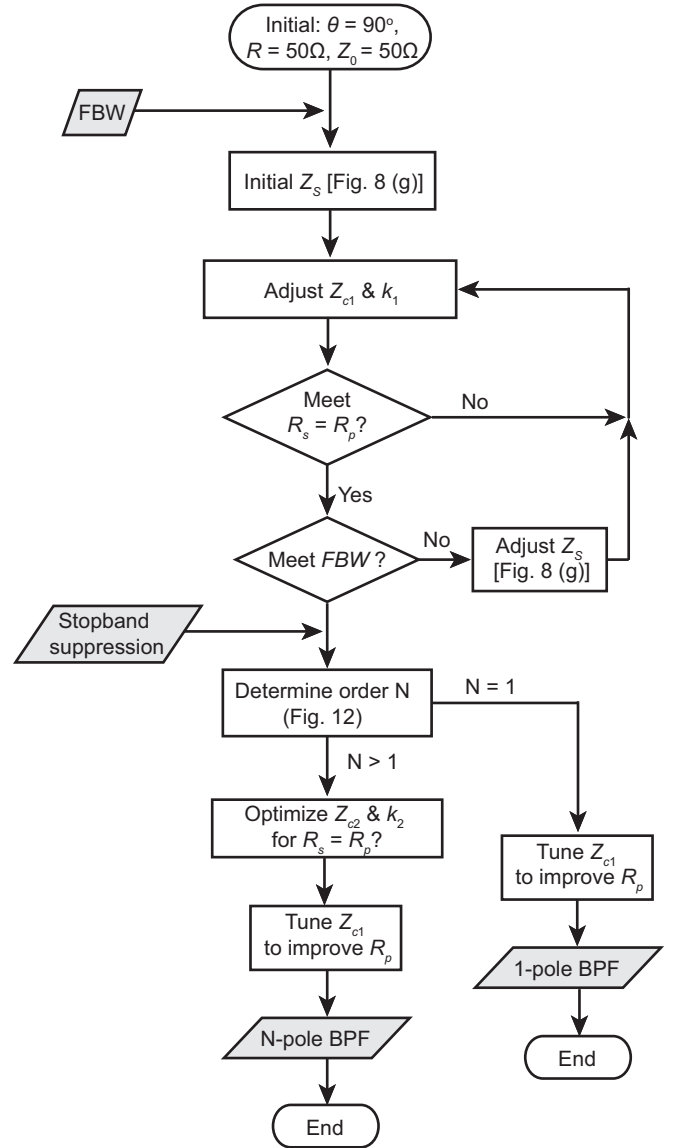


Fig. 13. Working flow of the design and optimization process.

be clearly identified. Interestingly, without the absorptive sections, the bandpass sections alone exhibit proper reflective filter responses.

Fig. 14(c) and Fig. 14(d) compare the transmission and reflection responses of the proposed quasi-absorptive filter [Fig. 6(a)] and those of [31] and [32]. To make a fair comparison, all three filters are designed for 1-pole response with the same 3-dB bandwidth.

The work of [31] is the only one that has fully reflectionless performance at all frequencies. As a result, the simulated $|S_{11}|$ is 0 and cannot be shown in the dB-scale plot of Fig. 14(d). The filter also outperforms both this work and the work of [32] in terms of close-in rejection due to the creation of transmission zeros very close to the passband edge. However, the proposed work generally exhibits better rejection than both filters in [31] and [32] at frequencies above approximately $1.3f_0$.

The main drawback of the work of [31], which are

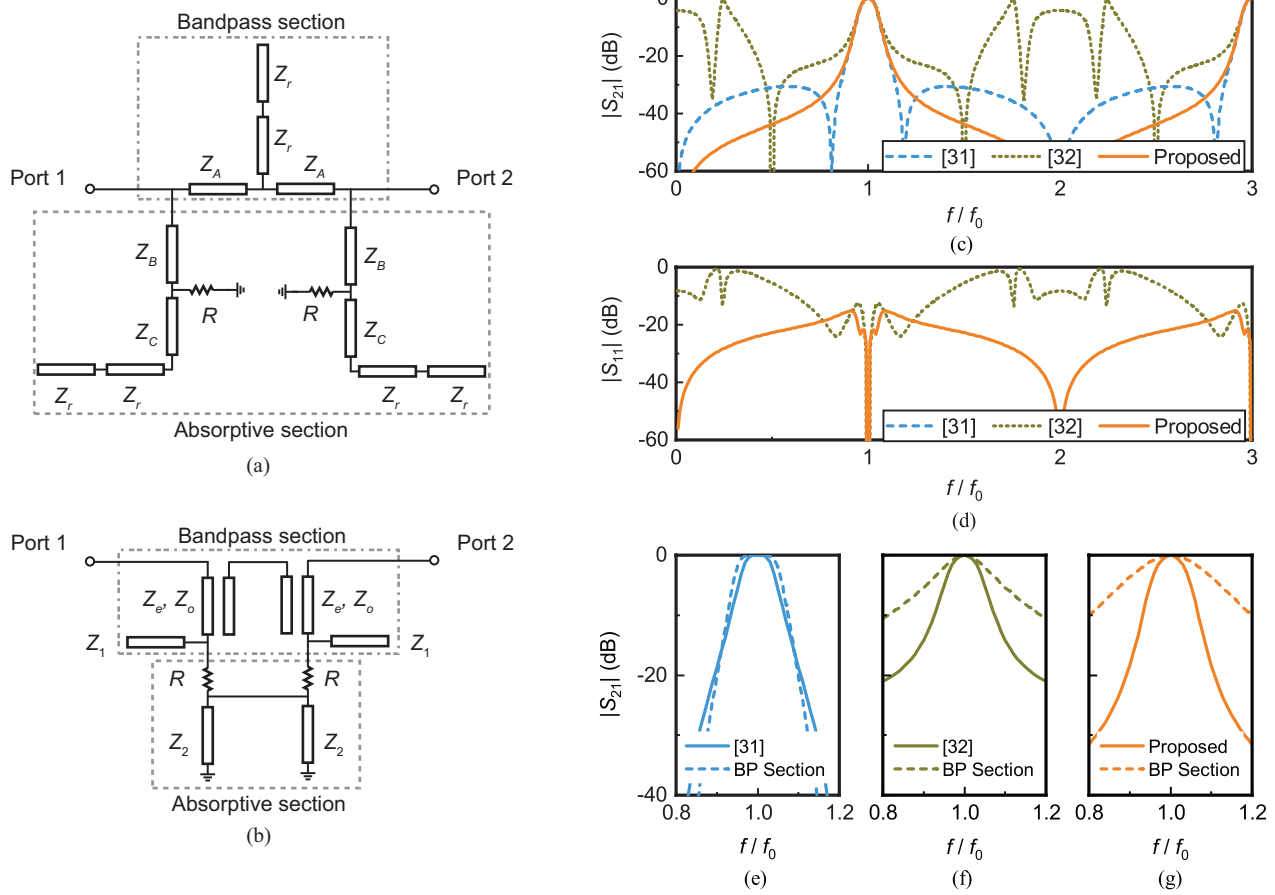


Fig. 14. (a) Distributed circuit model of the 1-pole quasi-absorptive BPF in [32]. (b) Distributed absorptive BPF presented in [31]. (c) A comparison of the simulated S_{21} between the proposed work and those of [32] and [31]. (d) A comparison of the simulated S_{11} between the proposed work and those of [32] and [31]. (e)–(g) A comparison of the simulated S_{21} between the overall absorptive filter and its bandpass section in [31], [32], and this work.

also acknowledged in [30] and [32], is the impractical circuit parameters due to the extremely high transmission-line impedance ratio as well as coupling coefficient of the coupled line sections even for moderate bandwidth. In addition, although a very deep close-in rejection can be created by increasing the order of the absorptive sections, the filter's far-out-of-band rejection is limited to an equivalent 1-pole response. A higher-order roll-off is yet to be demonstrated. In contrast, the proposed filter structures in this work can realize arbitrarily high orders by cascading more coupled lines in the bandpass sections.

The low reflection and high stopband attenuation for the work of [32] can only hold near the passband. In the lower stopband (centered at dc) and upper stopband (centered at $2f_0$), the filter degenerates back to a reflective type. In contrast, the design presented in this paper can achieve quasi-absorptive responses across all the frequencies with improved passband selectivity and stopband rejection.

Fig. 14(e)–(f) show comparative studies of the three filters with and without the absorptive sections. As we demonstrated in Section III-A, the bandwidth of the proposed quasi-absorptive filter structure is much smaller than its bandpass section. We can see that this is true for the work of [32] and to a lesser extent also true for the work of [31].

In both [32] and this work, the much reduced bandwidth means that the filter design must start with a much wider bandpass filter. When realized with coupled lines, this can lead to unwieldy component values. Although the work of [31] exhibits only slightly bandwidth reduction, we should note that it uses two coupled lines sections with signal power coupled from the same side. This configuration is known to result in a very small usable bandwidth, which explains why excessively high coupling coefficient is needed to realize moderate bandwidth in [31].

IV. EXPERIMENTAL VALIDATION

To validate the proposed design concepts, a class of quasi-absorptive BPFs with 1-, 2-, and 3-pole responses are designed and implemented on a 0.813-mm-thick Rogers 4003C substrate (relative permittivity of 3.55 and a loss tangent of 0.0027). The filters are designed at 2.45 GHz with a 3-dB fractional bandwidth of 22%. Schematic simulations are performed using Keysight Advanced Design System software (ADS) and electromagnetic (EM) simulations are carried out using Ansys High-frequency Structure Simulator (HFSS). Fig. 15 shows the layout, pictures, and the measured frequency responses of the filters.

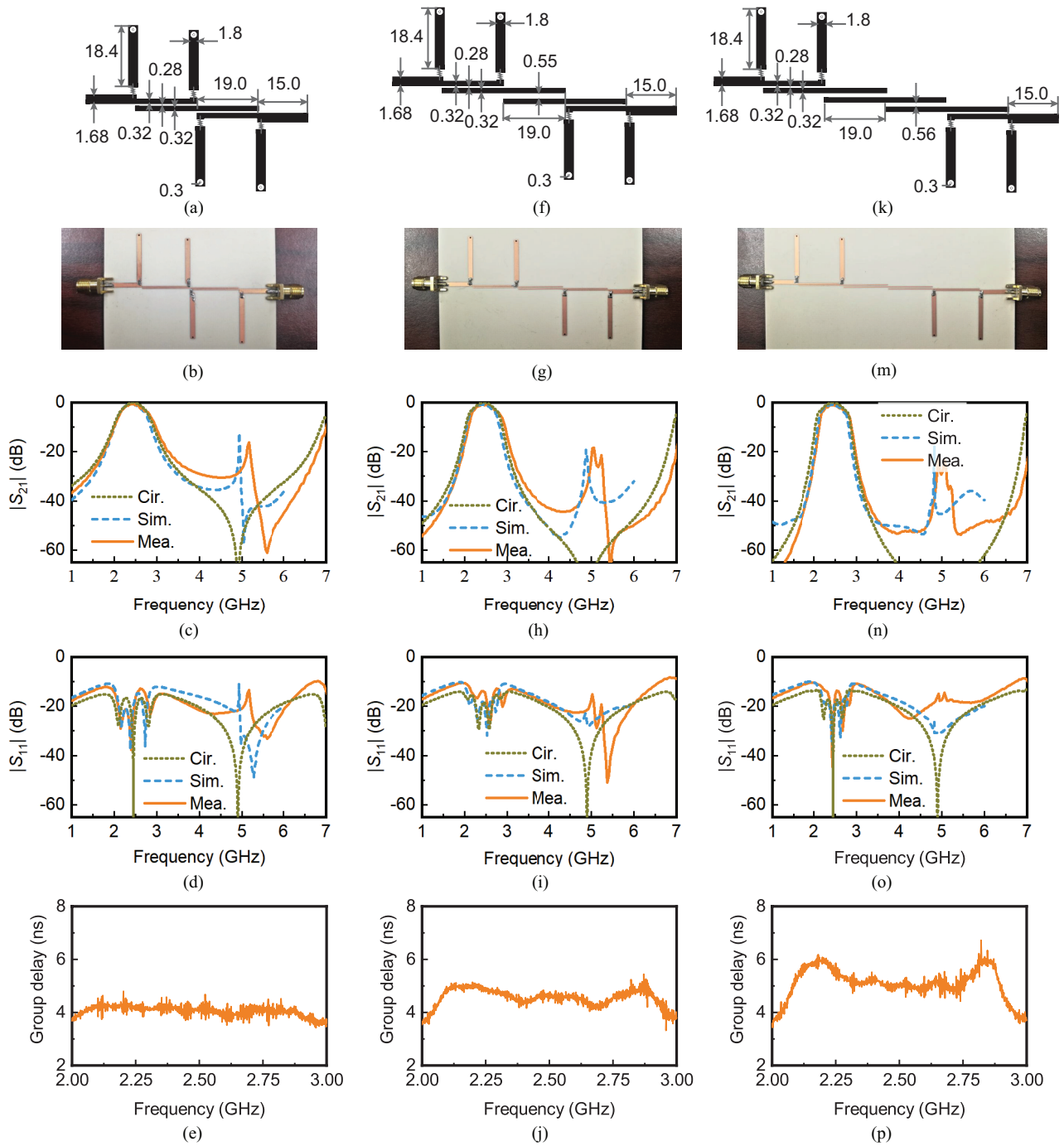


Fig. 15. (a) The layout and (b) a picture of the 1-pole quasi-absorptive BPF. (c) Circuit, simulation, and measured $|S_{21}|$ of the 1-pole quasi-absorptive BPF. (d) Circuit, simulation, and measured $|S_{11}|$ of the 1-pole quasi-absorptive BPF. (e) Measured group delay of the 1-pole quasi-absorptive BPF. (f) The layout and (g) a picture of the 2-pole quasi-absorptive BPF. (h) Circuit, simulation, and measured $|S_{21}|$ of the 2-pole quasi-absorptive BPF. (i) Circuit, simulation, and measured $|S_{11}|$ of the 2-pole quasi-absorptive BPF. (j) Measured group delay of the 2-pole quasi-absorptive BPF. (k) The layout and (m) a picture of the 3-pole quasi-absorptive BPF. (n) Circuit, simulation, and measured $|S_{21}|$ of the 3-pole quasi-absorptive BPF. (o) Circuit, simulation, and measured $|S_{11}|$ of the 3-pole quasi-absorptive BPF. (p) Measured group delay of the 3-pole quasi-absorptive BPF.

Following the procedures outlined in Fig. 13, the optimized circuit parameters of the 1-pole quasi-absorptive BPF are found to be $Z_s = 22.5 \Omega$, $Z_{c1} = 92 \Omega$, $k_1 = 1.55$, $R = 50 \Omega$, $\theta = 90^\circ$, and $Z_0 = 50 \Omega$ for an equi-ripple-reflection response. Using ADS's built-in microstrip line primitives, the simulated S_{11} is better than -17 dB up to 6.5 GHz, covering both the passband and the stopband. The full-wave simulated

performance is slightly worse in terms of absorption with a worst case S_{11} of -14 dB. This is primarily because the EM simulation takes into account the effects of discontinuities in the microstrip structures.

The measured insertion loss [Fig. 15(c)] is 0.6 dB at 2.45 GHz, and the measured 3-dB bandwidth is 2.2–2.75 GHz ($FBW = 22.5\%$). Due to fabrication and component value

tolerances, the measured reflection coefficient [Fig. 15 (d)] is slightly worse than that of the EM simulation. The worst case in-band S_{11} is -13 dB at 2.7 GHz. The measured group delay [Fig. 15 (e)] in the passband varies from 3.9 ns to 4.3 ns, viz., in-band group delay variation smaller than 0.4 ns.

The 2-pole filter [Fig. 15 (f)–(g)] is designed by inserting a coupled lines section in the bandpass section. The optimized values for the coupled lines are $Z_{c2} = 100 \Omega$ and $k_2 = 1.32$. In the range of 1–6.6 GHz, the measured S_{11} in Fig. 15 (i) is better than -10.7 dB across all frequencies and better than -13.5 dB in the passband. The insertion loss at the center frequency is measured to be 0.9 dB. The measured 3-dB bandwidth is 2.2–2.78 GHz ($FBW = 23.6\%$). The measured group delay [Fig. 15 (j)] within the 3 dB passband range is between 4.2 ns and 4.9 ns, viz., the group delay variation is lower than 0.7 ns.

The 3-pole filter [Fig. 15 (k)–(m)] is constructed by simply adding another section of coupled lines (Z_{c2}, k_2). The measured S_{11} in Fig. 15 (o) is better than -10 dB in the range of 1–6.7 GHz. The maximum in-band reflection is measured to be -13.5 dB. The measured insertion loss is 1.1 dB at 2.45 GHz. The measured 3-dB bandwidth is 2.2–2.76 GHz ($FBW = 22.8\%$). The measured group delay variation within the 3 dB passband range is lower than 0.9 ns, i.e., in-band group delay between 4.8 ns and 5.7 ns.

In all three cases, the measured results agree very well with the simulations except at around $2f_0$. In schematic simulations, full suppression at $2f_0$ can be attained due to the transmission zeros (f_{p1} and f_{p5}) from the absorptive coupled lines even though the bandpass section has spurious transmission at $2f_0$. In practice, however, parasitics and fabrication tolerances in the practical distributed circuit result in slight deviations of f_{p1} and f_{p5} from $2f_0$ and a corresponding degradation in the absorption. Nevertheless, all the simulated and measured results show predicted quasi-absorptive behavior in both passband and stopband, which well validates the proposed absorptive filter design concept. Note that the all-band return loss in the circuit analysis is better than 17 dB for the implemented 1-, 2-, and 3-pole filters. In the practical layout implementations, however, it decreases from 13 dB to 10 dB as the filter order increases from one to three. Such degradation is due to the increased parasitic effect as the filter order increases and will limit the maximum order of the practical filters.

V. CONCLUSION

In this paper, we have presented a new high-order distributed absorptive bandpass filter design that can achieve two-port quasi-absorptive responses over a wide frequency range. The essential building block of such filters is a coupled lines section loaded with two resonant absorptive stubs. We show that the bandwidth of the proposed absorptive filters are primarily determined by the absorptive coupled lines. As a result, higher-order response can be achieved by simply increasing the order of the bandpass section. A set of quasi-absorptive filters with various orders have been designed and measured to validate the proposed absorptive filter design methodology.

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